

Figure 1

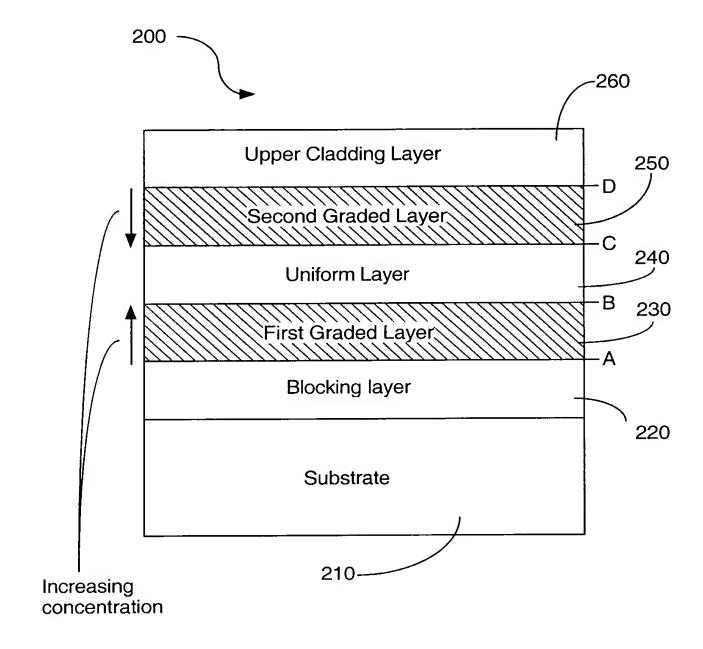
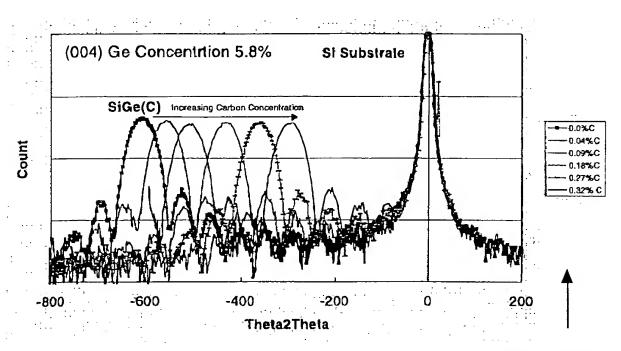


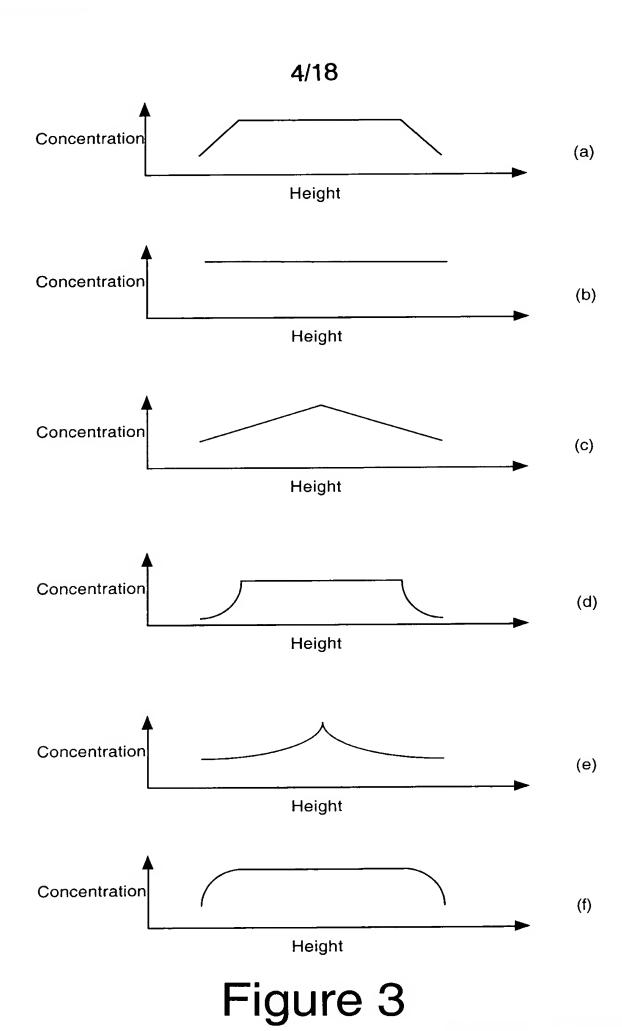
Figure 2A

## X-Ray Photoelctron Deffraction Graph of a Si Substrate and SiGeC Layers with Different C Concentrations



Approximate concentrations of substitutional carbon atoms

Figure 2B



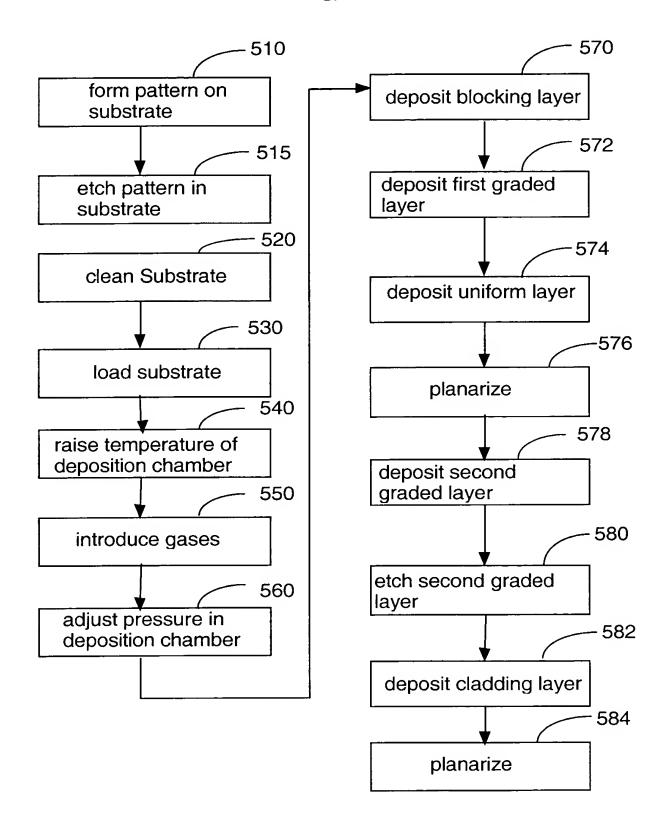


Figure 4

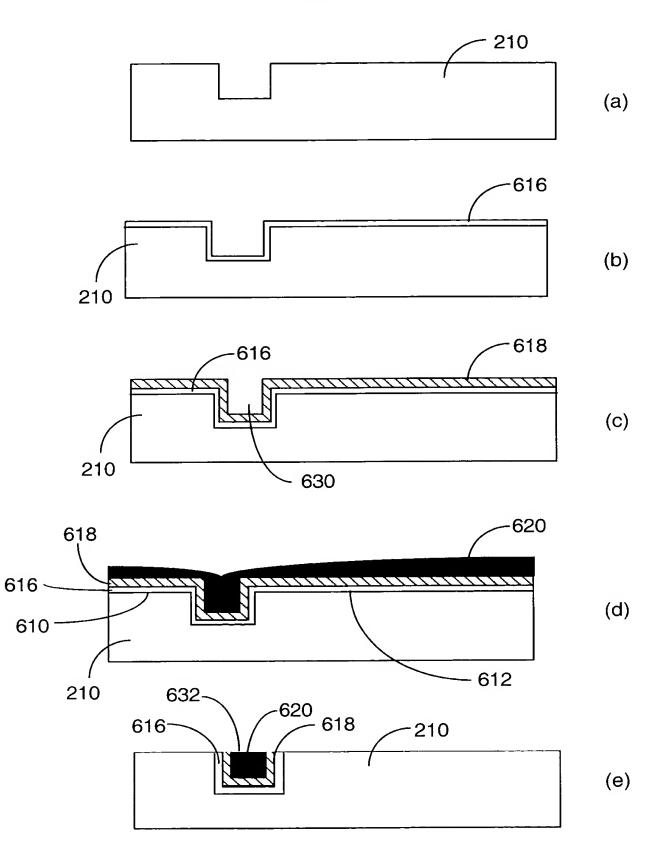


Figure 5



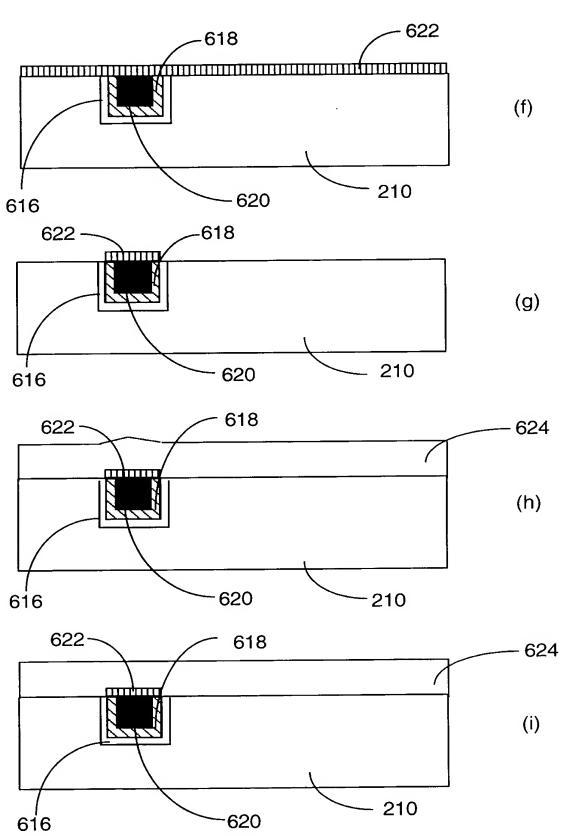
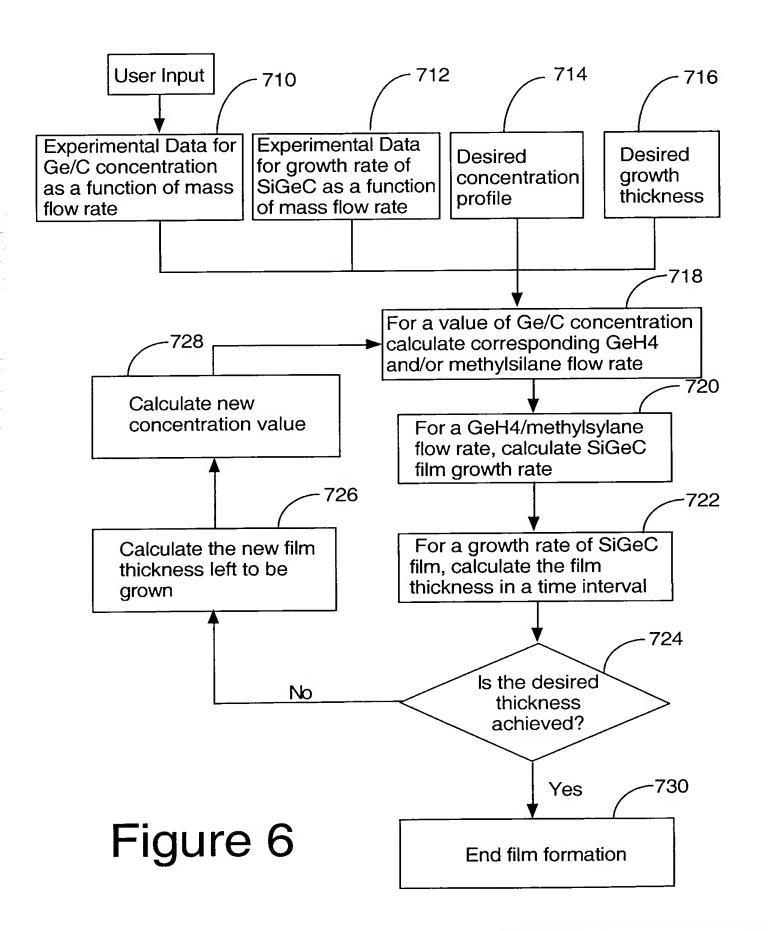
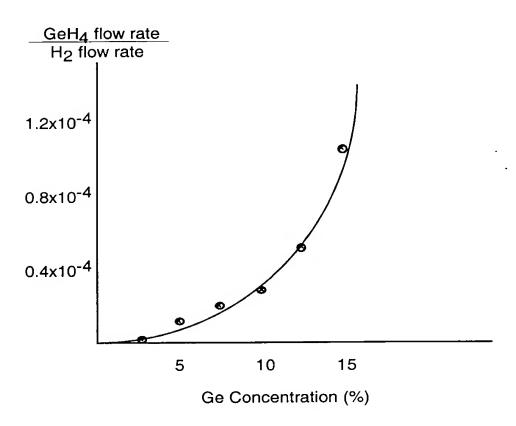


Figure 5





## Figure 7A

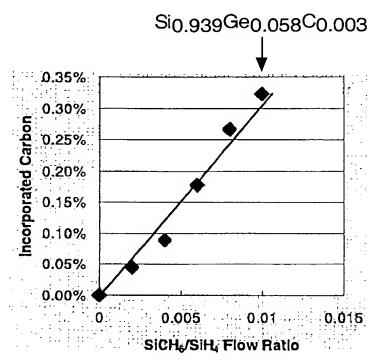


Figure 7B

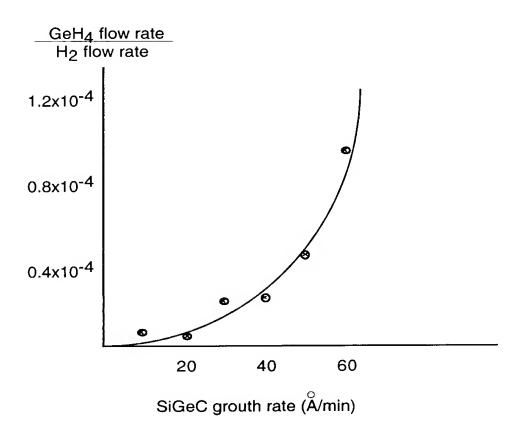
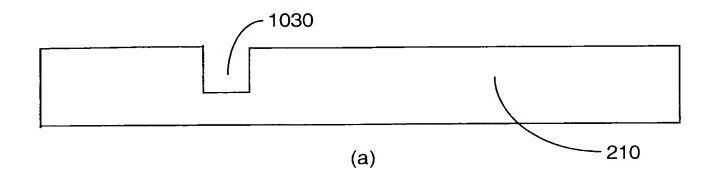
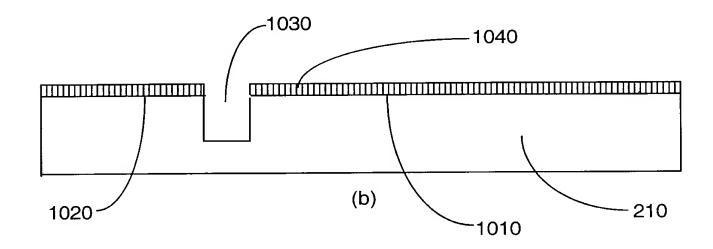
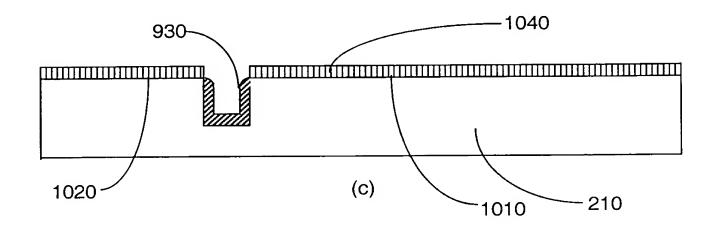


Figure 8









## Figure 9

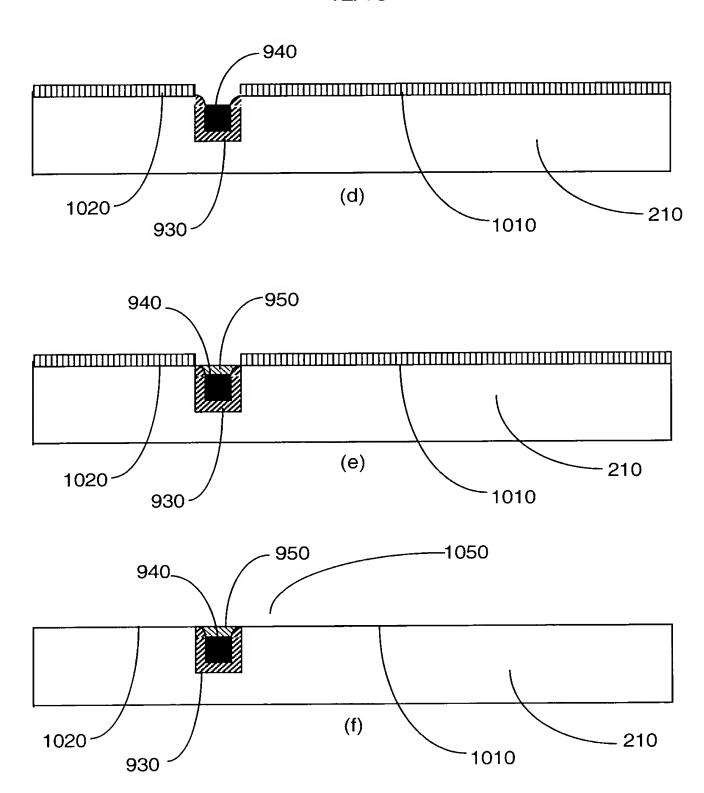


Figure 9

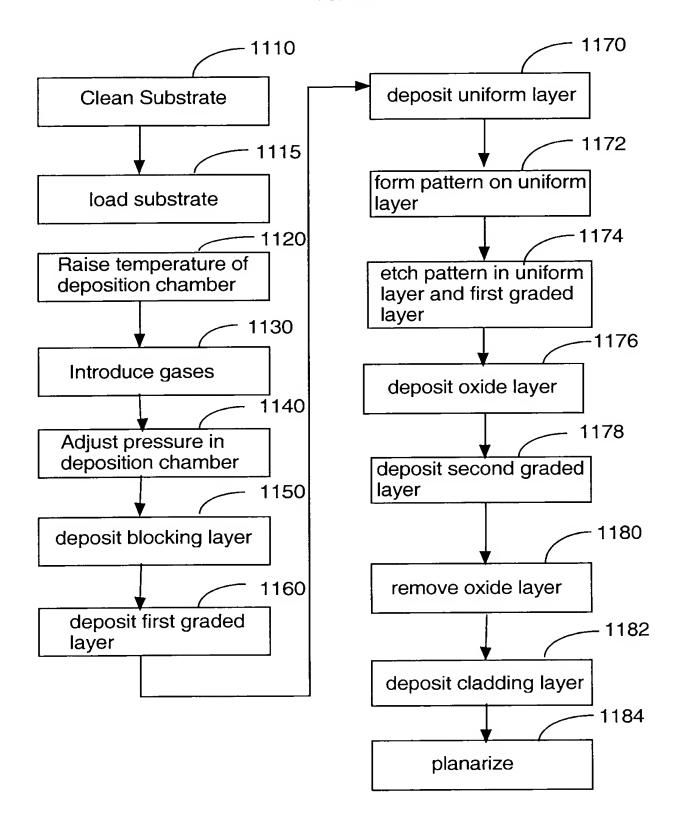
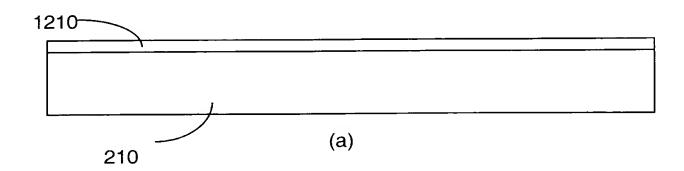
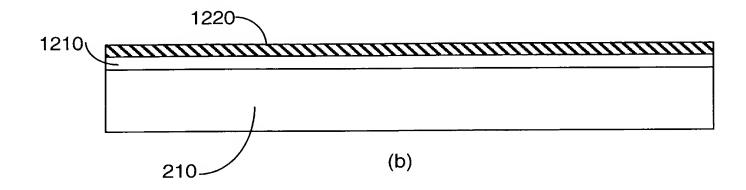


Figure 10





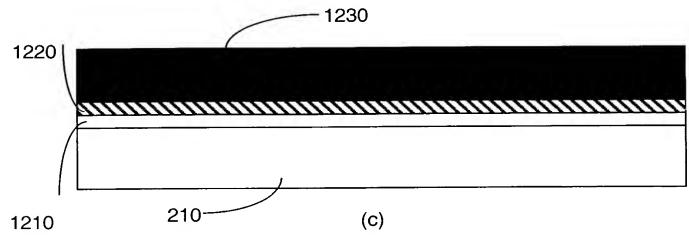
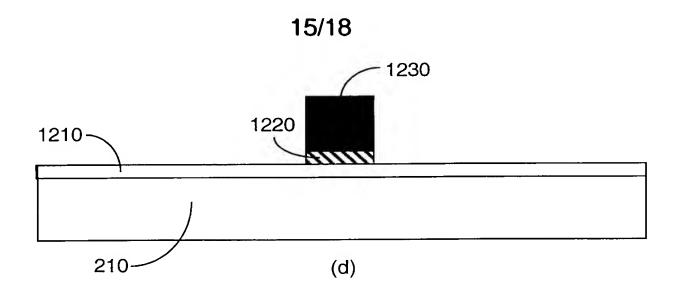
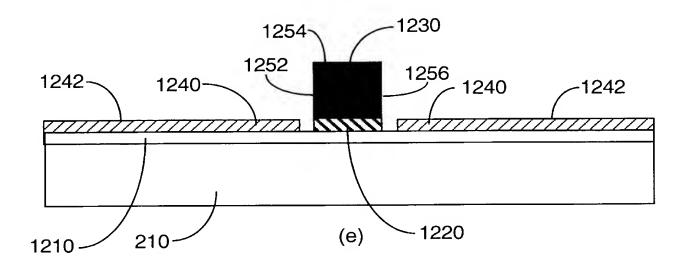


Figure 11





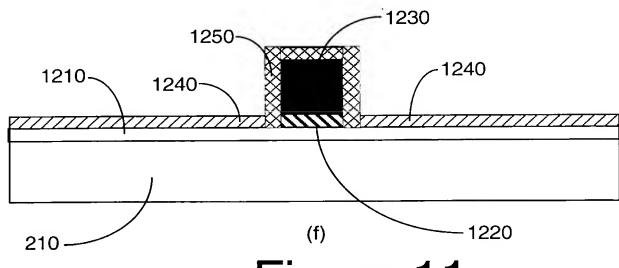
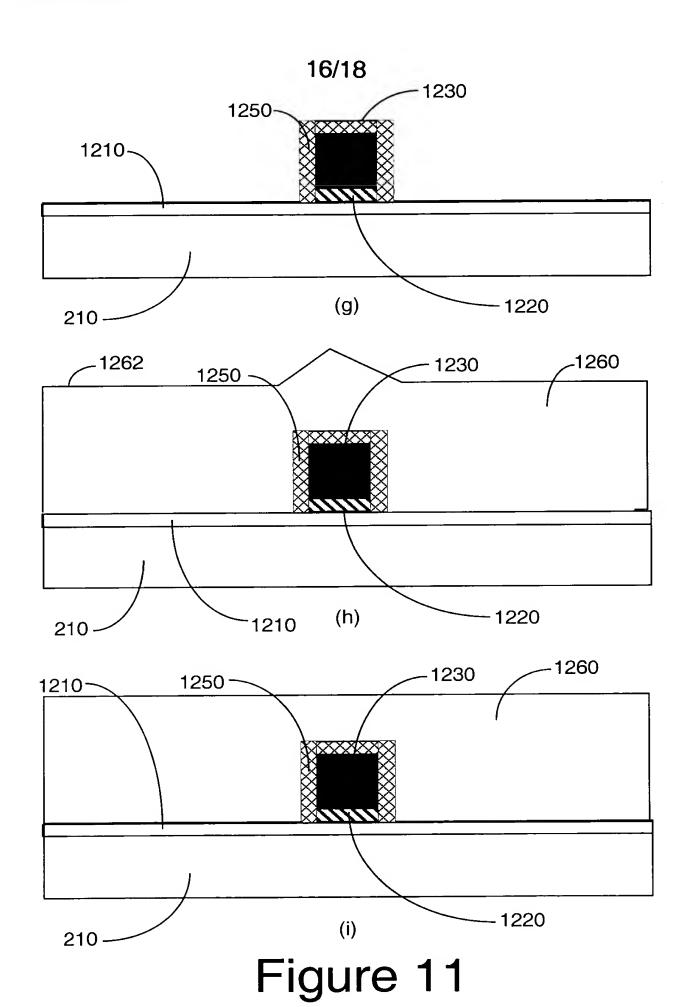


Figure 11



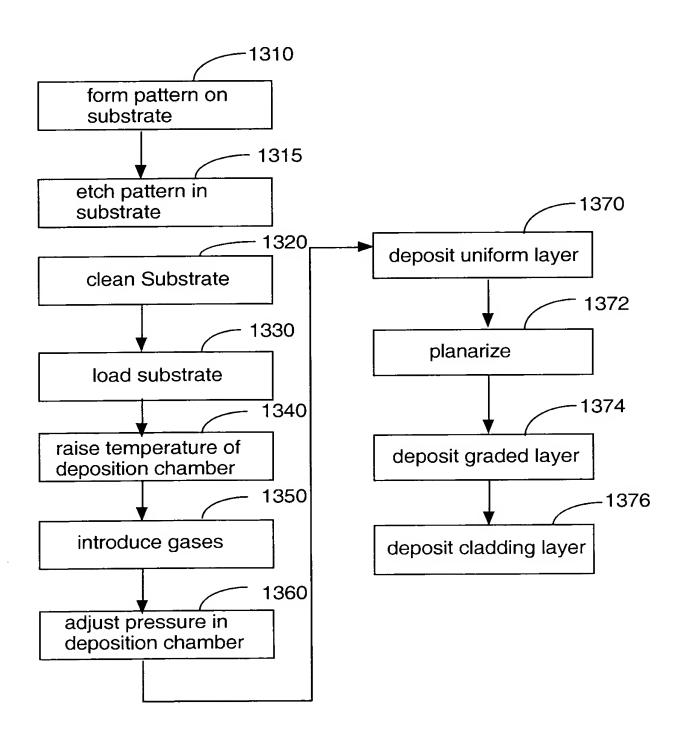


Figure 12

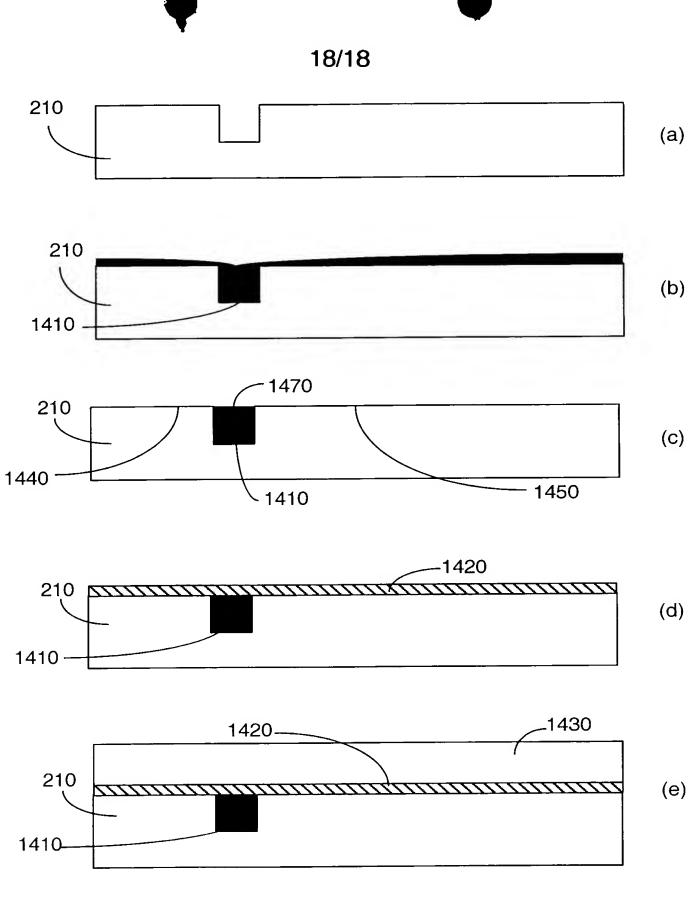


Figure 13